## Automotive N-Channel 40 V (D-S) $175{ }^{\circ} \mathrm{C}$ MOSFET

| PRODUCT SUMMARY |  |
| :--- | :---: |
| $\mathrm{V}_{\mathrm{DS}}(\mathrm{V})$ | 40 |
| $\mathrm{R}_{\mathrm{DS}(\text { on })}(\Omega)$ at $\mathrm{V}_{\mathrm{GS}}=10 \mathrm{~V}$ | 0.009 |
| $\mathrm{I}_{\mathrm{D}}(\mathrm{A})$ | 50 |
| Configuration | Single |

## FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET® Power MOSFET
- Package with Low Thermal Resistance
- $100 \% \mathrm{R}_{\mathrm{g}}$ and UIS Tested
- AEC-Q101 Qualified ${ }^{\text {d }}$



## ORDERING INFORMATION

| Package | TO-252 |
| :--- | :--- |
| Lead $(\mathrm{Pb})$-free and Halogen-free | SQD50N04-09H-GE3 |


| ABSOLUTE MAXIMUM RATINGS ( $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$, unless otherwise noted) |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| PARAMETER |  | SYMBOL | LIMIT | UNIT |
| Drain-Source Voltage |  | $\mathrm{V}_{\mathrm{DS}}$ | 40 | V |
| Gate-Source Voltage |  | $\mathrm{V}_{\mathrm{GS}}$ | $\pm 20$ |  |
| Continuous Drain Current | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}{ }^{\text {a }}$ | ID | 50 | A |
|  | $\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ |  | 40 |  |
| Continuous Source Current (Diode Conduction) ${ }^{\text {a }}$ |  | $\mathrm{I}_{\text {s }}$ | 50 |  |
| Pulsed Drain Current ${ }^{\text {b }}$ |  | $\mathrm{I}_{\mathrm{DM}}$ | 200 |  |
| Single Pulse Avalanche Energy | $\mathrm{L}=0.1 \mathrm{mH}$ | $\mathrm{I}_{\text {AS }}$ | 39 |  |
| Single Pulse Avalanche Current |  | $\mathrm{EAS}_{\text {S }}$ | 76 | mJ |
| Maximum Power Dissipation ${ }^{\text {b }}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | PD | 83 | W |
|  | $\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ |  | 27 |  |
| Operating Junction and Storage Temperature Range |  | $\mathrm{T}_{\mathrm{J}}, \mathrm{T}_{\text {stg }}$ | -55 to +175 | ${ }^{\circ} \mathrm{C}$ |


| PARAMETER |  | SYMBOL | LIMIT | UNIT |
| :---: | :---: | :---: | :---: | :---: |
| Junction-to-Ambient | PCB Mount ${ }^{\text {c }}$ | $\mathrm{R}_{\mathrm{thJA}}$ | 50 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Junction-to-Case (Drain) |  | $\mathrm{R}_{\mathrm{thJC}}$ | 1.8 |  |

## Notes

a. Package limited.
b. Pulse test; pulse width $\leq 300 \mu \mathrm{~s}$, duty cycle $\leq 2 \%$.
c. When mounted on $1^{\prime \prime}$ square PCB (FR-4 material).
d. Parametric verification ongoing.

SPECIFICATIONS ( $T_{C}=25^{\circ} \mathrm{C}$, unless otherwise noted)


## Notes

a. Pulse test; pulse width $\leq 300 \mu \mathrm{~s}$, duty cycle $\leq 2 \%$.
b. Guaranteed by design, not subject to production testing.
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS $\left(\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\right.$, unless otherwise noted)



Transfer Characteristics



Transfer Characteristics


Transconductance


TYPICAL CHARACTERISTICS $\left(\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\right.$, unless otherwise noted)


Gate Charge


Source Drain Diode Forward Voltage



On-Resistance vs. Junction Temperature


On-Resistance vs. Gate-to-Source Voltage


Drain Source Breakdown vs. Junction Temperature

THERMAL RATINGS $\left(\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\right.$, unless otherwise noted)


Safe Operating Area


Normalized Thermal Transient Impedance, Junction-to-Ambient

THERMAL RATINGS $\left(\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\right.$, unless otherwise noted)


Normalized Thermal Transient Impedance, Junction-to-Case

## Note

- The characteristics shown in the two graphs
- Normalized Transient Thermal Impedance Junction-to-Ambient ( $25^{\circ} \mathrm{C}$ )
- Normalized Transient Thermal Impedance Junction-to-Case ( $25^{\circ} \mathrm{C}$ )
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size $1^{\prime \prime} \times 1^{\prime \prime} \times 0.062$ ", double sided with 2 oz. copper, $100 \%$ on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

[^0] Package Information

## TO-252AA Case Outline



|  | MILLIMETERS |  | INCHES |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| DIM. | MIN. | MAX. | MIN. | MAX. |  |
| A | 2.18 | 2.38 | 0.086 | 0.094 |  |
| A1 | - | 0.127 | - | 0.005 |  |
| b | 0.64 | 0.88 | 0.025 | 0.035 |  |
| b2 | 0.76 | 1.14 | 0.030 | 0.045 |  |
| b3 | 4.95 | 5.46 | 0.195 | 0.215 |  |
| C | 0.46 | 0.61 | 0.018 | 0.024 |  |
| C2 | 0.46 | 0.89 | 0.018 | 0.035 |  |
| D | 5.97 | 6.22 | 0.235 | 0.245 |  |
| D1 | 4.10 | - | 0.161 | - |  |
| E | 6.35 | 6.73 | 0.250 | 0.265 |  |
| E1 | 4.32 | - | 0.170 | - |  |
| H | 9.40 | 10.41 | 0.370 | 0.410 |  |
| e | 2.28 BSC | 0.090 | BSC |  |  |
| e1 | 4.56 BSC | 0.180 | BSC |  |  |
| L | 1.40 | 1.78 | 0.055 | 0.070 |  |
| L3 | 0.89 | 1.27 | 0.035 | 0.050 |  |
| L4 | - | 1.02 | - | 0.040 |  |
| L5 | 1.01 | 1.52 | 0.040 | 0.060 |  |
| ECN: T13-0592-Rev. A, 02-Sep-13 |  |  |  |  |  |
| DWG: 6019 |  |  |  |  |  |

Note

- Dimension L3 is for reference only.


## RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads
Dimensions in Inches/(mm)

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